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100-tap Digital Potentiometer (POT) with Buffered Wiper

Description

The CAT5111 is a single digital POT designed as an electronic replacement for mechanical potentiometers. Ideal for automated adjustments on high volume production lines, they are also well suited for applications where equipment requiring periodic adjustment is either difficult to access or located in a hazardous or remote environment.

The CAT5111 contains a 100-tap series resistor array connected between two terminals R_H and R_L . An up/down counter and decoder that are controlled by three input pins, determines which tap is connected to the wiper, R_{WB} . The CAT5111 wiper is buffered by an op amp that operates rail to rail. The wiper setting, stored in non-volatile memory, is not lost when the device is powered down and is automatically recalled when power is returned. The wiper can be adjusted to test new system values without effecting the stored setting. Wiper-control of the CAT5111 is accomplished with three input control pins, $\overline{\text{CS}}$, U/ $\overline{\text{D}}$, and $\overline{\text{INC}}$. The $\overline{\text{INC}}$ input increments the wiper in the direction which is determined by the logic state of the U/ $\overline{\text{D}}$ input. The $\overline{\text{CS}}$ input is used to select the device and also store the wiper position prior to power down.

The digital POT can be used as a buffered voltage divider. For applications where the potentiometer is used as a 2-terminal variable resistor, please refer to the CAT5113. The buffered wiper of the CAT5111 is not compatible with that application.

Features

- 100-position Linear Taper Potentiometer
- Non-volatile EEPROM Wiper Storage; Buffered Wiper
- Low Power CMOS Technology
- Single Supply Operation: 2.5 V 6.0 V
- Increment Up/Down Serial Interface
- Resistance Values: $10 \text{ k}\Omega$, $50 \text{ k}\Omega$ and $100 \text{ k}\Omega$
- Available in PDIP, SOIC, TSSOP and MSOP Packages
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- Automated Product Calibration
- Remote Control Adjustments
- · Offset, Gain and Zero Control
- Tamper-proof Calibrations
- Contrast, Brightness and Volume Controls
- · Motor Controls and Feedback Systems
- Programmable Analog Functions



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SOIC-8 V SUFFIX CASE 751BD



MSOP-8 Z SUFFIX CASE 846AD

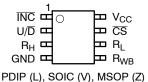


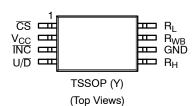
PDIP-8 L SUFFIX CASE 646AA



TSSOP-8 Y SUFFIX CASE 948AL

PIN CONFIGURATIONS





PIN FUNCTION

Pin Name	Function		
INC	Increment Control		
U/D	Up/Down Control		
R _H	Potentiometer High Terminal		
GND	Ground		
R _{WB}	Buffered Wiper Terminal		
R_{L}	Potentiometer Low Terminal		
CS	Chip Select		
V _{CC}	Supply Voltage		

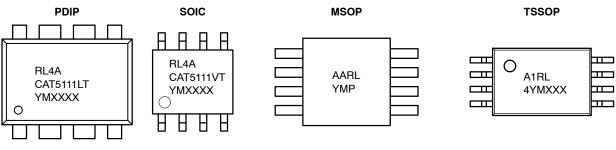
ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

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DEVICE MARKING INFORMATION



R = Resistance:

 $2 = 10 \text{ k}\Omega$

 $4 = 50 \text{ k}\Omega$

 $5 = 100 \text{ k}\Omega$

L = Assembly Location

4 = Lead Finish - NiPdAu

A = Product Revision (Fixed as "A")

CAT5111L = Device Code (PDIP)

CAT5111V = Device Code (SOIC)

T = Temperature Range (Industrial)

Y = Production Year (Last Digit)

M = Production Month (1-9, A, B, C)

XXXX = Last Four Digits of Assembly Lot Number

AARL = CAT5111ZI-10-T3

AAPT = CAT5111ZI-50-T3

AAPX = CAT5111ZI-00-T3

Y = Production Year (Last Digit)

M = Production Month (1-9, A, B, C)

P = Product Revision

A1 = Device Code

R = Resistance: $2 = 10 \text{ k}\Omega$

 $4 = 50 \text{ k}\Omega$

 $5 = 100 \text{ k}\Omega$

L = Assembly Location

4 = Lead Finish – NiPdAu

Y = Production Year (Last Digit)

M = Production Month (1-9, A, B, C)

XXX = Last Three Digits of

Assembly Lot Number

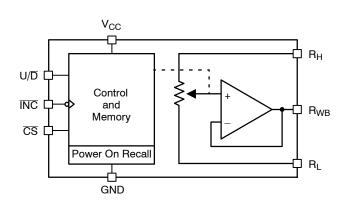


Figure 1. Functional Diagram

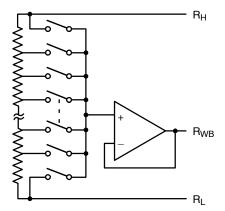


Figure 2. Electronic Potentiometer Implementation

Pin Description

INC: Increment Control Input

The \overline{INC} input (on the falling edge) moves the wiper in the up or down direction determined by the condition of the U/\overline{D} input.

U/D: Up/Down Control Input

The U/\overline{D} input controls the direction of the wiper movement. When in a high state and \overline{CS} is low, any high-to-low transition on \overline{INC} will cause the wiper to move one increment toward the R_H terminal. When in a low state and \overline{CS} is low, any high-to-low transition on \overline{INC} will cause the wiper to move one increment towards the R_L terminal.

R_H: High End Potentiometer Terminal

 $R_{\rm H}$ is the high end terminal of the potentiometer. It is not required that this terminal be connected to a potential greater than the $R_{\rm L}$ terminal. Voltage applied to the $R_{\rm H}$ terminal cannot exceed the supply voltage, $V_{\rm CC}$ or go below ground, GND.

R_{WB}: Wiper Potentiometer Terminal (Buffered)

 R_{WB} is the buffered wiper terminal of the potentiometer. Its position on the resistor array is controlled by the control inputs, $\overline{INC},\,U/\overline{D}$ and $\overline{CS}.$

RL: Low End Potentiometer Terminal

 $R_{\rm L}$ is the low end terminal of the potentiometer. It is not required that this terminal be connected to a potential less than the $R_{\rm H}$ terminal. Voltage applied to the $R_{\rm L}$ terminal cannot exceed the supply voltage, $V_{\rm CC}$ or go below ground, GND. $R_{\rm L}$ and $R_{\rm H}$ are electrically interchangeable.

CS: Chip Select

The chip select input is used to activate the control input of the CAT5111 and is active low. When in a high state, activity on the $\overline{\rm INC}$ and U/ $\overline{\rm D}$ inputs will not affect or change the position of the wiper.

Device Operation

The CAT5111 operates like a digitally controlled potentiometer with R_H and R_L equivalent to the high and low terminals and R_{WB} equivalent to the mechanical potentiometer's wiper. There are 100 available tap positions including the resistor end points, R_H and R_L . There are 99 resistor elements connected in series between the R_H and R_L terminals. The wiper terminal is connected to one of the 100 taps and controlled by three inputs, \overline{INC} , U/\overline{D} and \overline{CS} . These inputs control a seven-bit up/down counter whose output is decoded to select the wiper position. The selected wiper position can be stored in nonvolatile memory using the \overline{INC} and \overline{CS} inputs.

With $\overline{\text{CS}}$ set LOW the CAT5111 is selected and will respond to the U/ $\overline{\text{D}}$ and $\overline{\text{INC}}$ inputs. HIGH to LOW transitions on $\overline{\text{INC}}$ will increment or decrement the wiper (depending on the state of the U/ $\overline{\text{D}}$ input and seven-bit counter). The wiper, when at either fixed terminal, acts like its mechanical equivalent and does not move beyond the last position. The value of the counter is stored in nonvolatile memory whenever $\overline{\text{CS}}$ transitions HIGH while the $\overline{\text{INC}}$ input is also HIGH. When the CAT5111 is powered-down, the last stored wiper counter position is maintained in the nonvolatile memory. When power is restored, the contents of the memory are recalled and the counter is set to the value stored.

With INC set low, the CAT5111 may be de-selected and powered down without storing the current wiper position in nonvolatile memory. This allows the system to always power up to a preset value stored in nonvolatile memory.

Table 1. OPERATION MODES

INC	CS	U/D	Operation
High to Low	Low	High	Wiper toward R _H
High to Low	Low	Low	Wiper toward R _L
High	Low to High	Х	Store Wiper Position
Low	Low to High	Х	No Store, Return to Standby
Х	High	Х	Standby

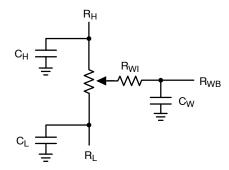


Figure 3. Potentiometer Equivalent Circuit

Table 2. ABSOLUTE MAXIMUM RATINGS

Parameters	Ratings	Units
Supply Voltage V _{CC} to GND	-0.5 to +7	V
Inputs CS to GND	-0.5 to V _{CC} +0.5	V
INC to GND	-0.5 to V _{CC} +0.5	V
U/D to GND	-0.5 to V _{CC} +0.5	V
R _H to GND	-0.5 to V _{CC} +0.5	V
R _L to GND	-0.5 to V _{CC} +0.5	V
R _{WB} to GND	-0.5 to V _{CC} +0.5	V
Operating Ambient Temperature Commercial ('C' or Blank suffix)	0 to 70	°C
Industrial ('I' suffix)	-40 to +85	°C
Junction Temperature	+150	°C
Storage Temperature	-65 to 150	°C
Lead Soldering (10 s max)	+300	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Table 3. RELIABILITY CHARACTERISTICS

Symbol	Parameter	Test Method	Min	Тур	Max	Units
V _{ZAP} (Note 1)	ESD Susceptibility	MIL-STD-883, Test Method 3015	2000			V
I _{LTH} (Notes 1, 2)	Latch-Up	JEDEC Standard 17	100			mA
T_DR	Data Retention	MIL-STD-883, Test Method 1008	100			Years
N _{END}	Endurance	MIL-STD-883, Test Method 1003	1,000,000			Stores

^{1.} This parameter is tested initially and after a design or process change that affects the parameter.

^{2.} Latch-up protection is provided for stresses up to 100 mA on address and data pins from -1 V to V_{CC} + 1 V

Table 4. DC ELECTRICAL CHARACTERISTICS (V_{CC} = +2.5 V to +6 V unless otherwise specified)

Symbol	Parameter	Conditions	Min	Тур	Max	Units
POWER SUPPL	Y		•	•		•
V _{CC}	Operating Voltage Range		2.5	-	6	٧
I _{CC1}	Supply Current (Increment)	$V_{CC} = 6 \text{ V, f} = 1 \text{ MHz, I}_{W} = 0$	_	=	200	μΑ
		$V_{CC} = 6 \text{ V}, f = 250 \text{ kHz}, I_W = 0$	_	-	100	μΑ
I _{CC2}	Supply Current (Write)	Programming, V _{CC} = 6 V	-	-	1000	μΑ
		V _{CC} = 3 V	-	-	500	μΑ
I _{SB1} (Note 4)	Supply Current (Standby)	$\frac{\overline{CS} = V_{CC} - 0.3 \text{ V}}{U/\overline{D}, \overline{INC} = V_{CC} - 0.3 \text{ V or GND}}$	=	75	150	μΑ
LOGIC INPUTS				•		•
I _{IH}	Input Leakage Current	V _{IN} = V _{CC}	_	-	10	μΑ
I _{IL}	Input Leakage Current	V _{IN} = 0 V	-	-	-10	μΑ
V _{IH1}	TTL High Level Input Voltage	4.5 V ≤ V _{CC} ≤ 5.5 V	2	-	V _{CC}	V
V _{IL1}	TTL Low Level Input Voltage		0	-	8.0	V
V _{IH2}	CMOS High Level Input Voltage	2.5 V ≤ V _{CC} ≤ 6 V	V _{CC} x 0.7	-	V _{CC} + 0.3	V
V_{IL2}	CMOS Low Level Input Voltage		-0.3	_	V _{CC} x 0.2	٧
POTENTIOMET	ER CHARACTERISTICS					
R _{POT}	Potentiometer Resistance	-10 Device		10		kΩ
		-50 Device		50		
		-00 Device		100		
	Pot. Resistance Tolerance				±20	%
V_{RH}	Voltage on R _H pin		0		V _{CC}	V
V_{RL}	Voltage on R _L pin		0		V _{CC}	V
	Resolution			1		%
INL	Integral Linearity Error	I _W ≤ 2 μA		0.5	1	LSB
DNL	Differential Linearity Error	I _W ≤ 2 μA		0.25	0.5	LSB
R _{OUT}	Buffer Output Resistance	$0.05 \text{ V}_{CC} \le \text{V}_{WB} \le 0.95 \text{ V}_{CC},$ $\text{V}_{CC} = 5 \text{ V}$			1	Ω
Гоит	Buffer Output Current	$0.05 \text{ V}_{CC} \le \text{V}_{WB} \le 0.95 \text{ V}_{CC},$ $\text{V}_{CC} = 5 \text{ V}$			3	mA
TC _{RPOT}	TC of Pot Resistance			300		ppm/°C
TC _{RATIO}	Ratiometric TC				20	ppm/°C
C _{RH} /C _{RL} /C _{RW}	Potentiometer Capacitances			8/8/25		pF
fc	Frequency Response	Passive Attenuator, 10 k Ω		1.7		MHz
V _{WB(SWING)}	Output Voltage Range	I _{OUT} ≤ 100 μA, V _{CC} = 5 V	0.01 V _{CC}		0.99 V _{CC}	

^{3.} This parameter is tested initially and after a design or process change that affects the parameter.

 ^{4.} Latch-up protection is provided for stresses up to 100 mA on address and data pins from -1 V to V_{CC} + 1 V
 5. l_W = source or sink
 6. These parameters are periodically sampled and are not 100% tested.

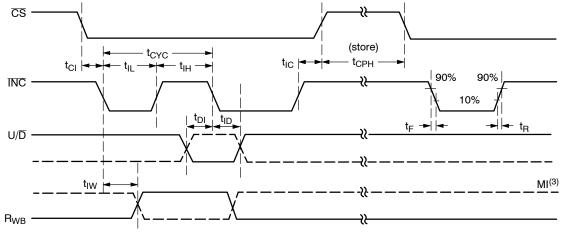
Table 5. AC TEST CONDITIONS

V _{CC} Range	$2.5 \text{ V} \leq \text{V}_{\text{CC}} \leq 6 \text{ V}$
Input Pulse Levels	0.2 V_{CC} to 0.7 V_{CC}
Input Rise and Fall Times	10 ns
Input Reference Levels	0.5 V _{CC}

Table 6. AC OPERATING CHARACTERISTICS (V_{CC} = +2.5 V to +6.0 V, V_H = V_{CC} , V_L = 0 V, unless otherwise specified)

Symbol	Parameter	Min	Typ (Note 7)	Max	Units
t _{Cl}	CS to INC Setup	100	-	-	ns
t _{DI}	U/D to INC Setup	50	-	=	ns
t _{ID}	U/D to INC Hold	100	-	=	ns
t _{IL}	ĪNC LOW Period	250	-	-	ns
t _{IH}	TNC HIGH Period	250	-	-	ns
t _{IC}	INC Inactive to CS Inactive	1	-	=	μs
t _{CPH}	CS Deselect Time (NO STORE)	100	-	=	ns
t _{CPH}	CS Deselect Time (STORE)	10	-	=	ms
t _{IW}	ĪNC to V _{OUT} Change	-	1	5	μs
tcyc	ĪNC Cycle Time	1	-	=	μs
t _R , t _F (Note 8)	INC Input Rise and Fall Time	=	-	500	μs
t _{PU} (Note 8)	Power-up to Wiper Stable	-	_	1	ms
t _{WR}	Store Cycle	-	5	10	ms

- 7. Typical values are for T_A = 25°C and nominal supply voltage.
 8. This parameter is periodically sampled and not 100% tested.
- 9. MI in the A.C. Timing diagram refers to the minimum incremental change in the W output due to a change in the wiper position.



APPLICATIONS INFORMATION

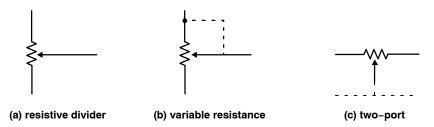


Figure 5. Potentiometer Configuration

Applications

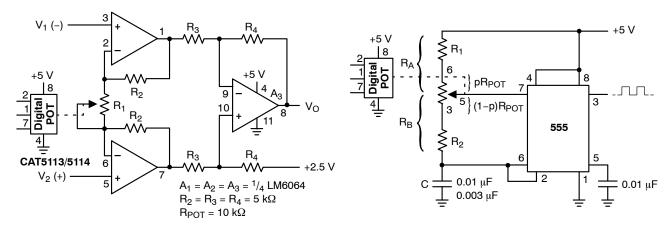


Figure 6. Programmable Instrumentation Amplifier

Figure 7. Programmable Sq. Wave Oscillator (555)

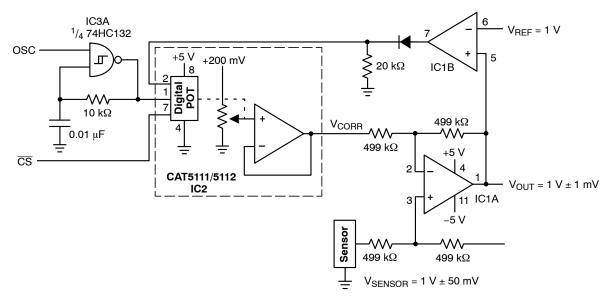


Figure 8. Sensor Auto Referencing Circuit

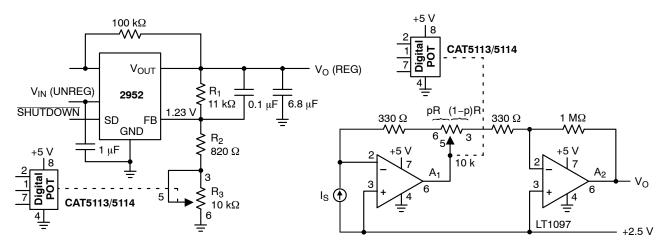


Figure 9. Programmable Voltage Regulator

Figure 10. Programmable I to V Converter

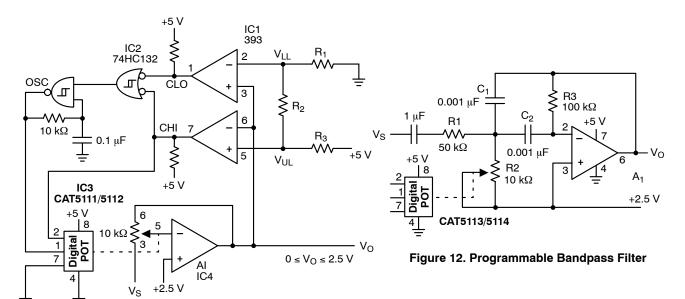


Figure 11. Automatic Gain Control

 $0 \le V_S \le 2.5 \text{ V}$

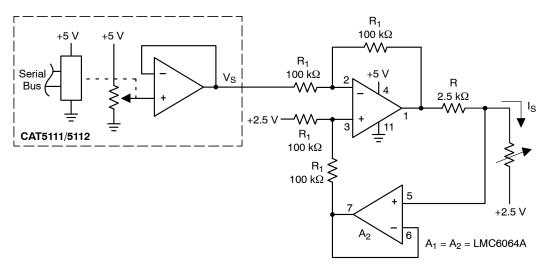


Figure 13. Programmable Current Source/Sink

Table 7. ORDERING INFORMATION

Orderable Part Number	Resistance (kΩ)	Lead Finish	Package-Pins	Shipping [†]
CAT5111LI-10-G	10			
CAT5111LI-50-G	50	NiPdAu PDIP-8 50 Units	50 Units / Tube	
CAT5111LI-00-G	100		(2)	
CAT5111VI-10-GT3	10			
CAT5111VI-50-GT3	50	NiPdAu	SOIC-8 (Pb-Free)	3000 / Tape & Reel
CAT5111VI-00-GT3	100			
CAT5111YI-10-GT3	10			
CAT5111YI-50-GT3	50	NiPdAu	iPdAu TSSOP-8 (Pb-Free)	3000 / Tape & Reel
CAT5111YI-00-GT3	100	(1 5-1 100)		
CAT5111ZI-10-T3	10			
CAT5111ZI-50-T3	50	Matte-Tin	MSOP-8 (Pb-Free)	3000 / Tape & Reel
CAT5111ZI-00-T3	100	1	(* = 1.155)	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{10.} For detailed information and a breakdown of device nomenclature and numbering systems, please see the ON Semiconductor Device Nomenclature document, TND310/D, available at www.onsemi.com.

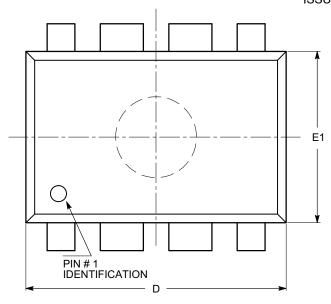
^{11.} All packages are RoHS compliant.

^{12.} Standard lead finish is NiPdAu, except MSOP package is Matte–Tin.

13. Contact factory for Matte–Tin finish availability for PDIP, SOIC and TSSOP packages.

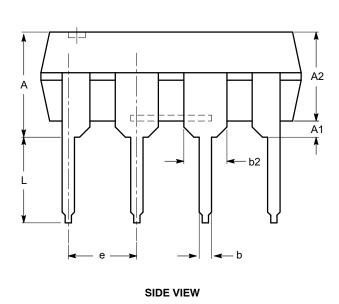
PACKAGE DIMENSIONS

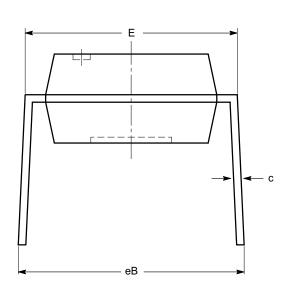
PDIP-8, 300 mils CASE 646AA ISSUE A



SYMBOL	MIN	NOM	MAX	
Α			5.33	
A1	0.38			
A2	2.92	3.30	4.95	
b	0.36	0.46	0.56	
b2	1.14	1.52	1.78	
С	0.20	0.25	0.36	
D	9.02	9.27	10.16	
Е	7.62	7.87	8.25	
E1	6.10	6.35	7.11	
е	2.54 BSC			
eB	7.87		10.92	
L	2.92	3.30	3.80	

TOP VIEW





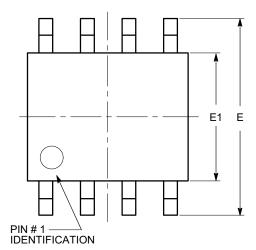
END VIEW

Notes:

- (1) All dimensions are in millimeters.
- (2) Complies with JEDEC MS-001.

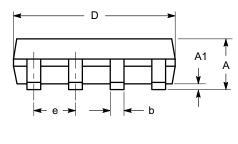
PACKAGE DIMENSIONS

SOIC 8, 150 mils CASE 751BD ISSUE O

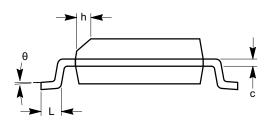


SYMBOL	MIN	NOM	MAX
А	1.35		1.75
A1	0.10		0.25
b	0.33		0.51
С	0.19		0.25
D	4.80		5.00
E	5.80		6.20
E1	3.80		4.00
е		1.27 BSC	
h	0.25		0.50
L	0.40		1.27
θ	0°		8°

TOP VIEW



SIDE VIEW



END VIEW

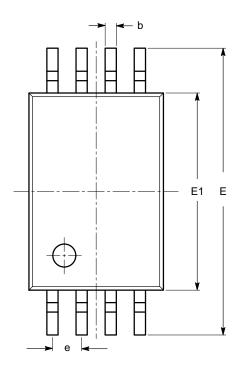
Notes:

- (1) All dimensions are in millimeters. Angles in degrees.(2) Complies with JEDEC MS-012.

PACKAGE DIMENSIONS

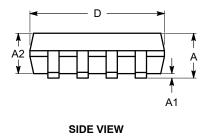
TSSOP8, 4.4x3

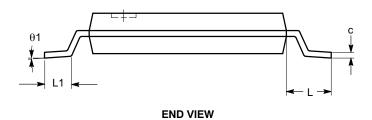
CASE 948AL ISSUE O



SYMBOL	MIN	NOM	MAX	
Α			1.20	
A1	0.05		0.15	
A2	0.80	0.90	1.05	
b	0.19		0.30	
С	0.09		0.20	
D	2.90	3.00	3.10	
E	6.30	6.40	6.50	
E1	4.30	4.40	4.50	
е	0.65 BSC			
L	1.00 REF			
L1	0.50	0.60	0.75	
θ	0°		8°	

TOP VIEW



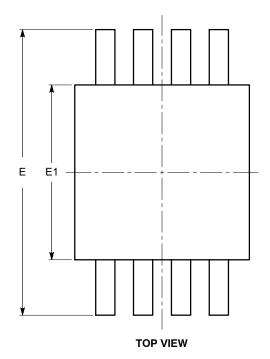


Notes:

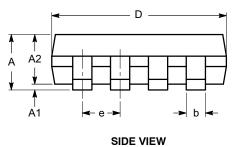
- (1) All dimensions are in millimeters. Angles in degrees.(2) Complies with JEDEC MO-153.

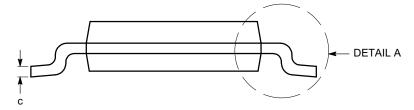
PACKAGE DIMENSIONS

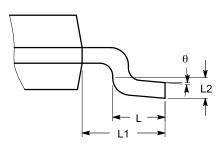
MSOP 8, 3x3 CASE 846AD ISSUE O



SYMBOL	MIN	NOM	MAX
Α			1.10
A1	0.05	0.10	0.15
A2	0.75	0.85	0.95
b	0.22		0.38
С	0.13		0.23
D	2.90	3.00	3.10
E	4.80	4.90	5.00
E1	2.90	3.00	3.10
е		0.65 BSC	
L	0.40	0.60	0.80
L1	0.95 REF		
L2	0.25 BSC		
θ	0°		6°







Notes:

- (1) All dimensions are in millimeters. Angles in degrees.(2) Complies with JEDEC MO-187.

END VIEW

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